

# THYRISTOR MODULE

## PK(PD,PE,KK)25F

TOP



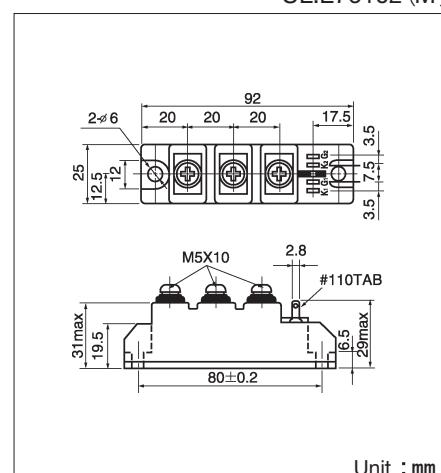
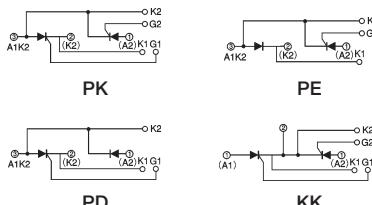
UL:E76102 (M)

Power Thyristor/Diode Module **PK25F** series are designed for various rectifier circuits and power controls. For your circuit application, following internal connections and wide voltage ratings up to 1,600V are available. High precision 25mm (1inch) width package and electrically isolated mounting base make your mechanical design easy.

- $I_{T(AV)}$  25A,  $I_{T(RMS)}$  39A,  $I_{TSM}$  580A
- $di/dt$  100 A/ $\mu$ s
- $dv/dt$  500V/ $\mu$ s

### (Applications)

Various rectifiers  
AC/DC motor drives  
Heater controls  
Light dimmers  
Static switches



Unit : mm

### ■ Maximum Ratings

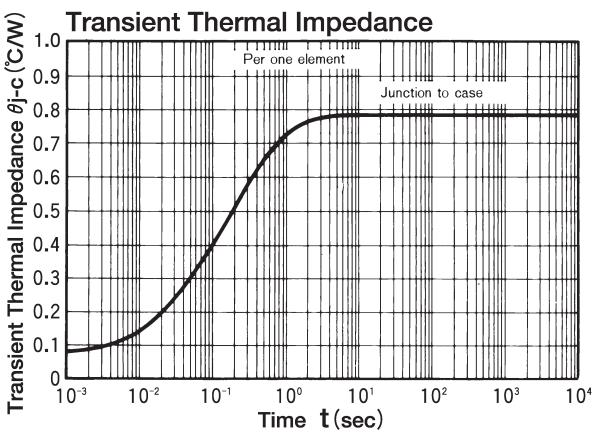
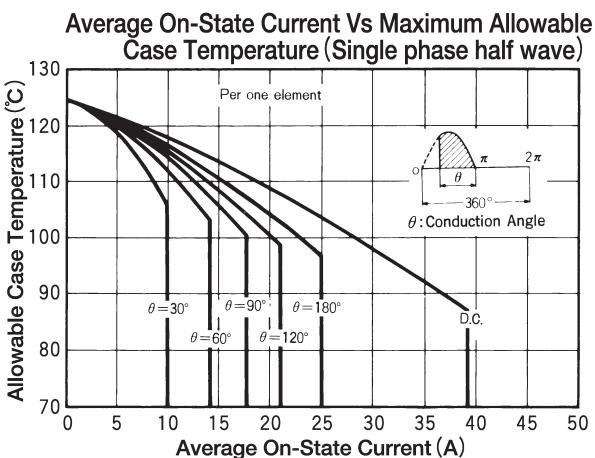
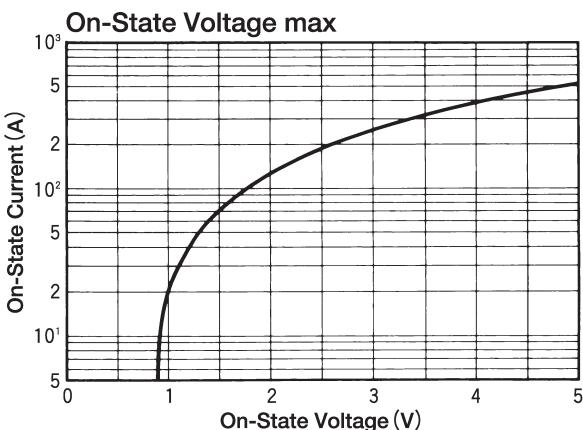
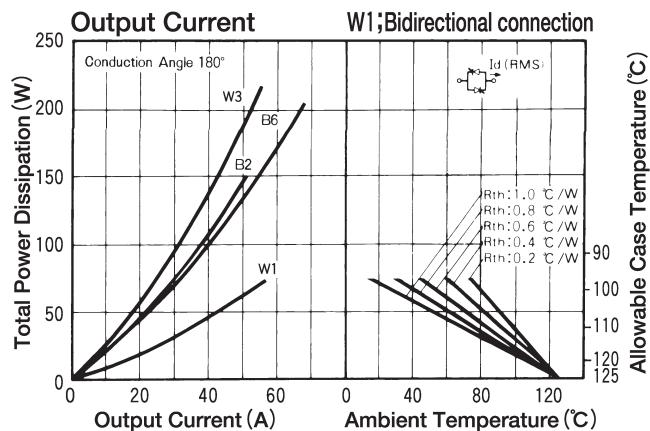
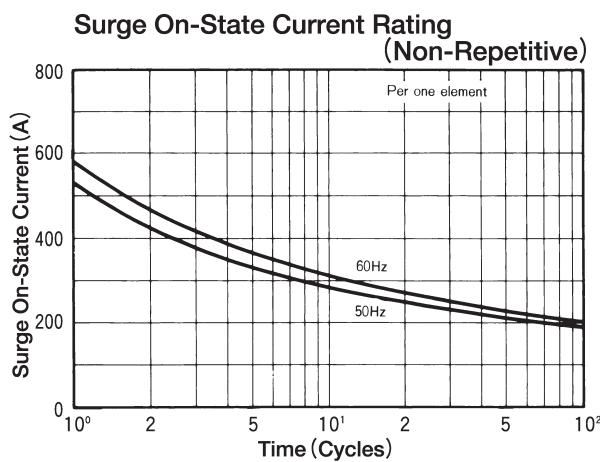
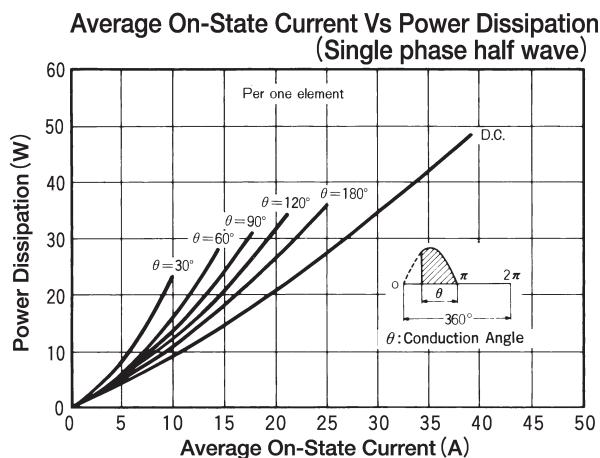
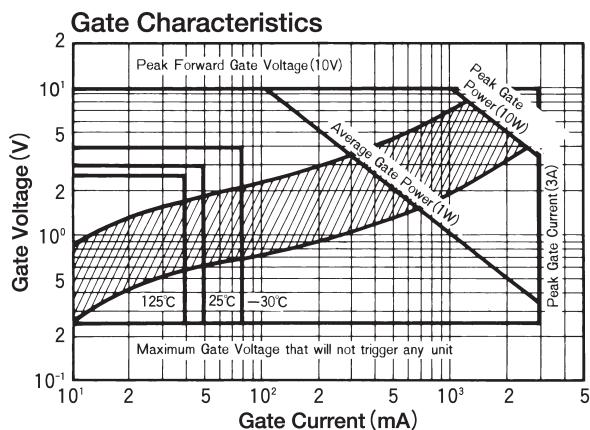
Symbol	Item	Ratings				Unit
		PK25F40 PD25F40 PE25F40 KK25F40	PK25F80 PD25F80 PE25F80 KK25F80	PK25F120 PD25F120 PE25F120 KK25F120	PK25F160 PD25F160 PE25F160 KK25F160	
$V_{RRM}$	* Repetitive Peak Reverse Voltage	400	800	1200	1600	V
$V_{RSM}$	* Non-Repetitive Peak Reverse Voltage	480	960	1300	1700	V
$V_{DRM}$	Repetitive Peak Off-State Voltage	400	800	1200	1600	V

Symbol	Item	Conditions	Ratings	Unit
$I_{T(AV)}$	* Average On-State Current	Single phase, half wave, 180° conduction, $T_c : 96^\circ\text{C}$	25	A
$I_{T(RMS)}$	* R.M.S. On-State Current	Single phase, half wave, 180° conduction, $T_c : 96^\circ\text{C}$	39	A
$I_{TSM}$	* Surge On-State Current	1/2 cycle, 50Hz/60Hz, peak Value, non-repetitive	530/580	A
$I^2t$	* $I^2t$	Value for one cycle of surge current	1400	$\text{A}^2\text{s}$
PGM	Peak Gate Power Dissipation		10	W
PG (AV)	Average Gate Power Dissipation		1	W
IFGM	Peak Gate Current		3	A
VF <sub>GM</sub>	Peak Gate Voltage (Forward)		10	V
VR <sub>GM</sub>	Peak Gate Voltage (Reverse)		5	V
$di/dt$	Critical Rate of Rise of On-State Current	$I_G = 100\text{mA}, T_j = 25^\circ\text{C}, V_D = 1/2 V_{DRM}, di/dt = 0.1\text{A}/\mu\text{s}$	100	$\text{A}/\mu\text{s}$
V <sub>ISO</sub>	* Isolation Breakdown Voltage (R.M.S.)	A.C. 1 minute	2500	V
T <sub>j</sub>	* Operating Junction Temperature		-40 ~ +125	°C
T <sub>stg</sub>	* Storage Temperature		-40 ~ +125	°C
Mounting Torque	Mounting (M5)	Recommended Value 1.5~2.5 (15~25)	2.7 (28)	N · m
	Terminal (M5)	Recommended Value 1.5~2.5 (15~25)	2.7 (28)	(kgf · cm)
	Mass		170	g

### ■ Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
$I_{DRM}$	Repetitive Peak Off-State Current, max.	at $V_{DRM}$ , single phase, half wave, $T_j = 125^\circ\text{C}$	10	mA
$I_{RRM}$	* Repetitive Peak Reverse Current, max.	at $V_{DRM}$ , single phase, half wave, $T_j = 125^\circ\text{C}$	10	mA
$V_{TM}$	* Peak On-State Voltage, max.	On-State Current 75A, $T_j = 25^\circ\text{C}$ Inst. measurement	1.55	V
$I_{GT}/V_{GT}$	Gate Trigger Current/Voltage, max.	$T_j = 25^\circ\text{C}, I_T = 1\text{A}, V_D = 6\text{V}$	50/3	mA/V
$V_{GD}$	Non-Trigger Gate, Voltage, min.	$T_j = 125^\circ\text{C}, V_D = 1/2 V_{DRM}$	0.25	V
tgt	Turn On Time, max.	$I_T = 25\text{A}, I_G = 100\text{mA}, T_j = 25^\circ\text{C}, V_D = 1/2 V_{DRM}, di/dt = 0.1\text{A}/\mu\text{s}$	10	$\mu\text{s}$
$dv/dt$	Critical Rate of Rise of Off-State Voltage, min.	$T_j = 125^\circ\text{C}, V_D = 2/3 V_{DRM}$ , Exponential wave.	500	$\text{V}/\mu\text{s}$
$I_H$	Holding Current, typ.	$T_j = 25^\circ\text{C}$	50	mA
$I_L$	Latching Current, typ.	$T_j = 25^\circ\text{C}$	100	mA
R <sub>th(j-c)</sub>	* Thermal Impedance, max.	Junction to case	0.78	°C/W

\* mark : Thyristor and Diode part. No mark : Thyristor part



B6; Six pulse bridge connection  
W3; Three phase bidirectional connection

B2; Two Pulse bridge connection

